



SURFACE MOUNT SCHOTTKY DIODE ARRAYS

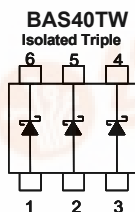
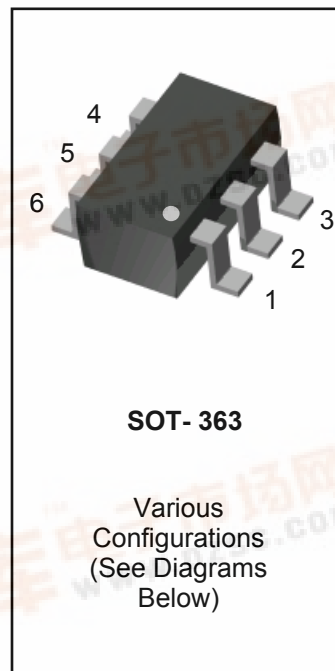
These devices feature electrically-isolated Schottky diodes connected in various configurations housed in a very small SOT-363 (SC70-6L)

FEATURES

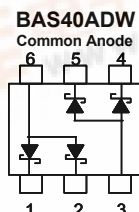
- Maximum forward voltage @ 10mA of 0.5V
- Maximum leakage current @ 25V of 1.0uA
- Reverse voltage rating of 40V
- Also available in lead-free plating (100% matte tin finish)

APPLICATIONS

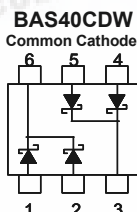
- Rail-to-rail ESD protection
- Overshoot and undershoot switching control
- Mobile phones and accessories
- Video game consoles connector ports



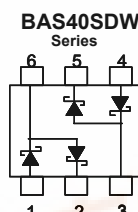
Marking Code: S40



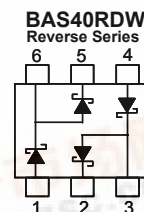
Marking Code: S42



Marking Code: S43



Marking Code: S44



Marking Code: S45

MAXIMUM RATINGS (Per Diode) $T_J = 25^\circ\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Repetitive Peak Reverse Voltage	V_{RRM}	40	V
Continuous Reverse Voltage	V_R	40	V
Continuous Forward Current	I_F	200	mA
Non-repetitive Peak Forward Current, $t = 1\text{sec}$, Square Wave	I_{FSM}	600	mA
Total Power Dissipation (Note 1)	P_{tot}	225	mW
Operating Junction Temperature Range	T_J	-55 to 125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to 125	$^\circ\text{C}$

Note 1. FR-5 Board 1.0 x 0.75 x 0.062 in.

THERMAL CHARACTERISTICS

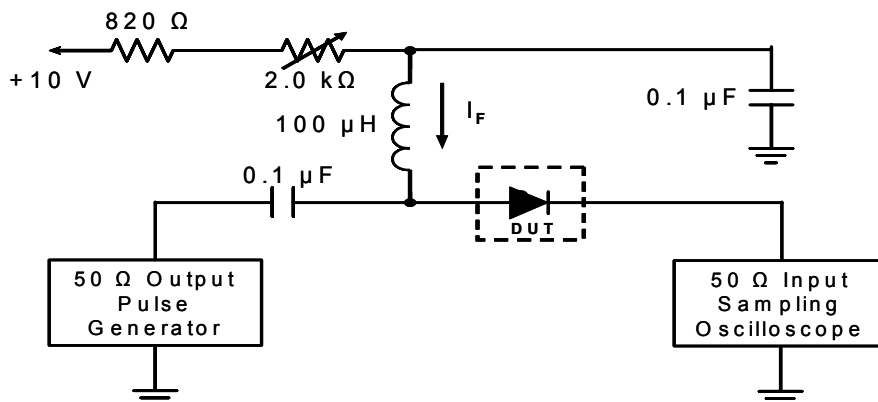
Characteristic	Symbol	Value	Units
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$



ELECTRICAL CHARACTERISTICS (Per Diode) $T_j = 25^\circ\text{C}$ Unless otherwise noted

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Breakdown Voltage (Note 1)	V_{BR}	$I_{BR} = 10\mu\text{A}$	40	-	-	V
Forward Voltage (Note 1)	V_F	$I_F = 1.0\text{mA}$	-	-	380	mV
		$I_F = 10\text{mA}$	-	-	500	
		$I_F = 40\text{mA}$	-	-	1000	
Reverse Leakage Current (Note 1)	I_R	$V_R = 25\text{V}$	-	-	1.0	μA
Total Capacitance	C_T	0Vdc Bias, $f = 1\text{MHz}$	-	-	5.0	pF
Reverse Recovery Time (See Figure 1)	t_{rr}	$I_F = 10\text{mA}$, $I_R = 10\text{mA}$ $R_L = 100\text{ Ohms}$; measured at $I_{R\text{rec}} = 1\text{mA}$	-	-	5.0	ns

Note 1. Short duration pulse to minimize self-heating effect



- Notes: 1. A 2.0k Ω variable resistor adjusted for a forward current (I_F) to 10mA
2. Input pulse is adjusted to $I_{R(\text{peak})}$ is equal to 10mA

Figure 1. REVERSE RECOVERY TIME EQUIVALENT TEST CIRCUIT



TYPICAL CHARACTERISTIC CURVES (Per Diode)

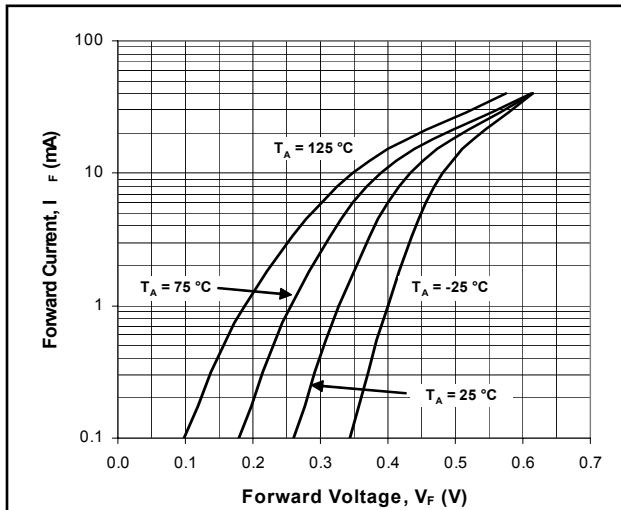


Fig. 2. Typical Forward Characteristics

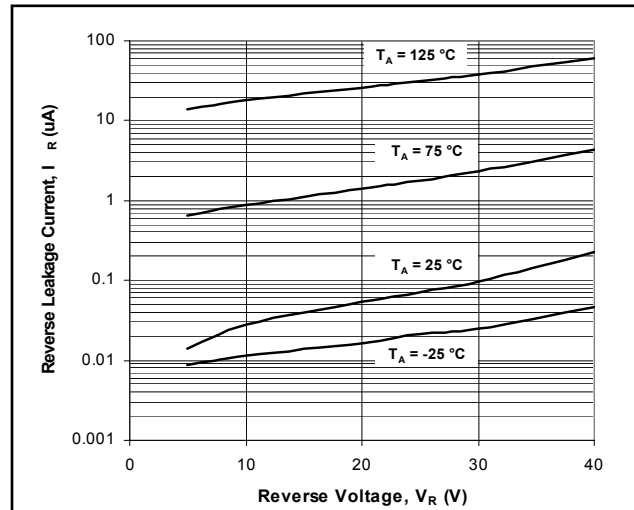


Fig. 3. Typical Reverse Characteristics

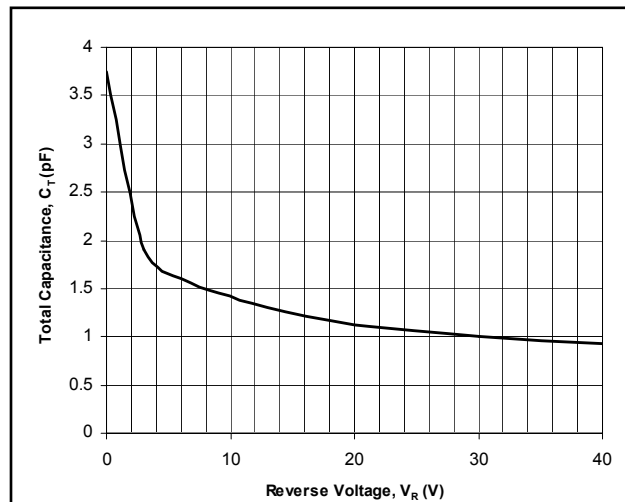
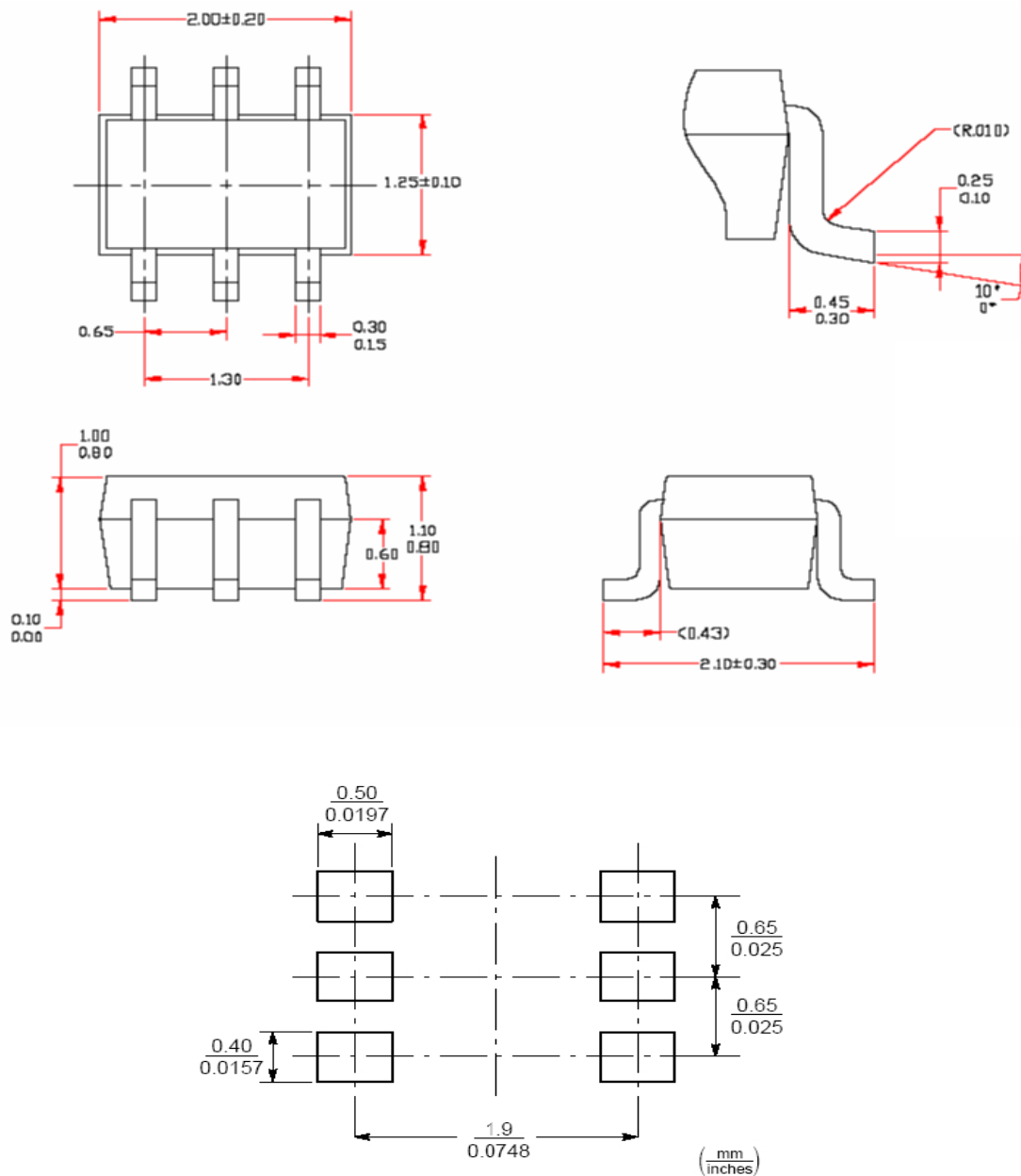


Fig. 4. Typical Capacitance



PACKAGE LAYOUT AND SUGGESTED PAD DIMENSIONS



ORDERING INFORMATION

BAS40xxx T/R7 - 7" reel, 3K units per reel

BAS40xxx T/R13 - 13" reel, 10K units per reel

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